

View Online at <https://aerobasegroup.com/nsn/5961-01-581-2531>

Inclosure Material:

Glass

End Application:

Ca70608-00 (19156) , receiver-transmitter

Mounting Facility Quantity:

2

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc and 60.0 breakdown voltage, collector to emitter, sustained

Current Rating Per Characteristic:

4.50 amperes collector current, dc

Power Rating Per Characteristic:

225.0 watts total power dissipation and 45.0 watts power output

Product Name:

Dwg: rf transistor; cage: 45 watts, 50 volts, pulsed avionics 960 - 1215 mhz; common base bipolar transistor

Precious Material And Location:

Thin-film metallization gold

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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